VIAGND

D=0.8 mm

W=W50

Subst="MSub1"

ViaLayout=Circular

S-PARAMETERS

S Param SP1 Step=10 MHz Center=7 GHz Span=6 GHz

MSub

MSUB MSub1 H=dielectric height Er=Arlon Er T=conductor height TanD=Arlon TanD



VAR MLIN parameters W50=1.382 mm L feed=2.5 mm

L shunt=5.558 mm {t} {o}

L serial=9.735 mm {t} {o}



VAR

schematic parameters

F center=7 GHz ZS=50 Ohm ZL=35+j*7 Ohm



VSWR

VSWR

VSWR1

VSWR1=vswr(S11)

VSWR2=vswr(S22)

VAR

substrate parameters

Arlon Er=2.55 Arlon TanD=0.0013 dielectric_height=0.508 mm conductor_height=35 um